

Trans IGBT Chip N-CH 2500V 30A 114mW 3-Pin(3+Tab) ISOPLUS I4-PAC

Manufacturer: <u>Littelfuse Inc</u>

Package/Case: ISOPLUSi4-Pak

Product Type: Thyristors

Lifecycle: Active



Images are for reference only

Inquiry

General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application
High power density	Switched-mode and resonant-mode power supplies
High frequency operation	Uninterruptible Power Supplies (UPS)
Low conduction losses	Laser and X-ray generators
MOS gate turn on for drive simplicity	
4000V electrical isolation	Capacitor discharge circuits
Advantages:	High voltage pulser circuits
Low gate drive requirements	High voltage test equipment
Space savings (eliminates multiple series-parallel lower voltage, lower current rated devices)	AC switches
Easy to mount	

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IXGN320N60A3

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IXYH50N65C3D1

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